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PATENT TRADEMARK OFFICE

Docket No.: 8733.325.00

(PATENT)

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C. Duong

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Sang In KIM, et al.

Application No.: 09/730,836

Group Art Unit: 2871

Filed: December 7, 2000

Examiner: T. Duong

For: LIQUID CRYSTAL DISPLAY AND
FABRICATING METHOD

AMENDMENT

Box Non-Fee Amendment
Commissioner for Patents
Washington, DC 20231

Dear Sir:

In response to the Office Action dated April 19, 2002 (Paper No. 3), please amend the above-identified U.S. patent application as follows:

In the Specification

On Page 3, paragraph beginning on line 21:

Referring now to Figure 1C, a metal layer is then deposited over the resulting structure, beneficially using either CVD or sputtering. In particular, the metal layer is formed over the ohmic contact layer 19 so as to make electrical contact with the ohmic contact layer 19. Beneficially, the metal layer is comprised of molybdenum (Mo), chrome (Cr), titanium (Ti) or tantalum (Ta), or of a molybdenum alloy such as MoW, MoTa or MoNb. The metal layer is then patterned by photolithography to expose the gate insulating film 15. Additionally, part of the metal layer over the gate electrode 13 and part of the ohmic contact layer 19 is removed, thereby

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